

15ELN15/25

(08 Marks)

First/Second Semester B.E. Degree Examination, Aug./Sept.2020 **Basic Electronics**

Time: 3 hrs.

TUTI

Max. Marks: 80

Note: Answer any FIVE full questions, choosing one full question from each module.

Module-1

What is diode? Explain the various parameters of diode in brief. (06 Marks) b. Draw the center tap full wave rectifier circuit and explain its operation. (05 Marks) c. Explain how zener diode can be used as a voltage regulator.

(05 Marks)

OR

a. Establish the relationship between α and β . (04 Marks)

b. Explain about common emitter characteristics with diagram.

Calculate α_{dc} and β_{dc} for the transistor if I_C is measured as 1 mA and I_B is 25 μ A. Also determine the new base current to give $I_C = 5$ mA. (04 Marks)

Module-2

Discuss the selection of operating point related to DC load line. (04 Marks)

b. Explain about voltage divider bias circuit with diagram. (06 Marks)

c. Calculate the minimum and maximum values of Ic and VcE for the base bias when $h_{FE(min)}=50$ and $h_{FE(max)}=60$. For circuit $V_{CC}=12V,\ R_{C}=2\ k\Omega$ and $R_{B}=150\ k$ (Assume silicon transistor). (06 Marks)

What is Op-Amp? Write the characteristics of ideal Op-Amp. (06 Marks)

b. Explain the Op-Amp integrator circuit with equation. (06 Marks)

An inverting amplifier has $R_1 = 20 \text{ k}\Omega$, $R_f = 100 \text{ k}\Omega$. Find the O/P voltage, I/P resistance and I/P current for an I/P voltage of 1V. (04 Marks)

Module-3

a. Perform the following operations:

i) $(110.1101)_2 = (?)_{10} \rightarrow \text{Binary to Decimal}$

ii) $(47.8125)_{10} = (?)_2 \rightarrow \text{Decimal to Binary}$

iii) $(31C.DE)_{16} = (?)_{10} \rightarrow \text{Hexadecimal to Decimal}$

iv) $(11010.101)_2 = (?)_{16} \rightarrow \text{Binary to Hexadecimal.}$ (08 Marks)

b. State and prove Demorgan's theorem with two variables. (04 Marks)

Construct a circuit for the expression X = AB + CD using :

i) Only NAND gates

ii) Only NOR gates. (04 Marks)

OR

a. Prove and implement by using basic gates:

i) A + AB = A + B

ii) (A + B) (A + C) = A + BC. (04 Marks)

b. Explain half adder circuit by using only NAND gates along with expression. (06 Marks)

c. Explain the basic laws of Boolean algebra. (06 Marks)

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7	a. b. c.	Explain about working of clocked SR Flip—Flop along with truth table. Mention the features of 8051.	(04 Marks) (08 Marks) (04 Marks)
8	a. b. c.	Briefly explain about SR latch with NAND gate structure.	(08 Marks) (06 Marks) (02 Marks)
9	a. b. c.	Define transducer. Explain about piezoelectric transducer and resistive transducer. If FM is represented by $V = 10 \sin{(8 \times 10^8 + 4 \sin{1000t})}$. Calculate: i) Carrier frequency (f _c)	
			(04 Marks)
10	a. b. c.	Explain elements of communication system along with block diagram.	(06 Marks) (06 Marks) (04 Marks)
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